Dual supply translating transceiver; auto direction sensing; 3-state

Rev. 01 — 8 June 2010

**Product data sheet** 

### 1. General description

The NXB0102 is a 2-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two data input-output ports (An and Bn), one output enable input (OE) and two supply pins ( $V_{CC(A)}$  and  $V_{CC(B)}$ ).  $V_{CC(A)}$  can be supplied at any voltage between 1.2 V and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V).

Pins An and OE are referenced to  $V_{CC(A)}$  and pins Bn are referenced to  $V_{CC(B)}$ . A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range:
  - ◆ V<sub>CC(A)</sub>: 1.2 V to 3.6 V and V<sub>CC(B)</sub>: 1.65 V to 5.5 V
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
  - ◆ HBM JESD22-A114E Class 2 exceeds 2500 V for A port
  - ♦ HBM JESD22-A114E Class 3B exceeds 15000 V for B port
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101E exceeds 1500 V
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C



## 3. Ordering information

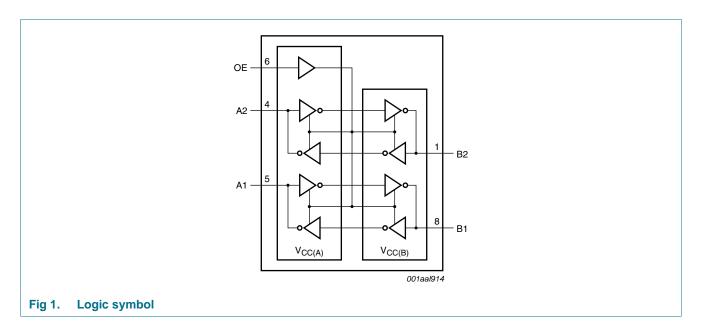
Type number	ing information Package	Package									
.,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,	Temperature range	Name	Description	Version							
NXB0102DP	–40 °C to +125 °C	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2							
NXB0102GT	–40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 $\times$ 1.95 $\times$ 0.5 mm	SOT833-1							
NXB0102GD	–40 °C to +125 °C	XSON8U	plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body $3 \times 2 \times 0.5$ mm	SOT996-2							
NXB0102GF	–40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.35 \times 1 \times 0.5$ mm	SOT1089							

## 4. Marking

Table 2.   Marking	
Type number	Marking code <sup>[1]</sup>
NXB0102DP	t02
NXB0102GT	t02
NXB0102GD	t02
NXB0102GF	t2

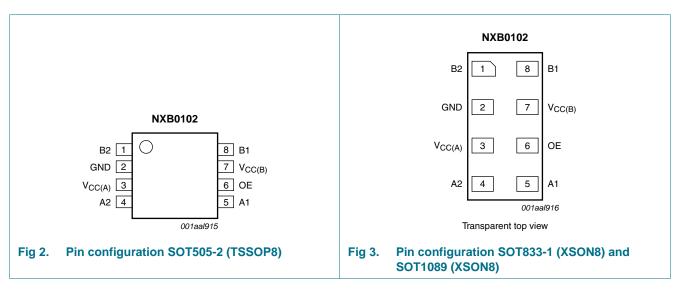
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

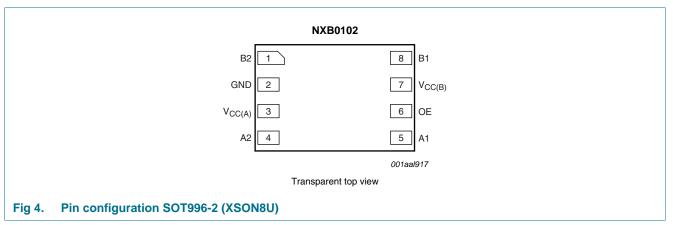
## 5. Functional diagram



#### **Pinning information** 6.

### 6.1 Pinning





### 6.2 Pin description

#### Table 3. **Pin description**

Symbol	Pin	Description
B2, B1	1, 8	data input or output (referenced to $V_{CC(B)}$ )
GND	2	ground (0 V)
V <sub>CC(A)</sub>	3	supply voltage A
A2, A1	4, 5	data input or output (referenced to $V_{CC(A)}$ )
OE	6	output enable input (active HIGH; referenced to $V_{CC(A)}$ )
V <sub>CC(B)</sub>	7	supply voltage B

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## 7. Functional description

#### Table 4. Function table<sup>[1]</sup>

Supply voltage		Input	Input/output	Input/output			
V <sub>CC(A)</sub> V <sub>CC(B)</sub>		OE	An	Bn			
1.2 V to $V_{CC(B)}$	1.65 V to 5.5 V	L	Z	Z			
1.2 V to V <sub>CC(B)</sub>	1.65 V to 5.5 V	Н	input or output	output or input			
GND <sup>[2]</sup>	GND <sup>[2]</sup>	Х	Z	Z			

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

[2] When either  $V_{CC(A)}$  or  $V_{CC(B)}$  is at GND level, the device goes into Power-down mode.

## 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC(A)</sub>	supply voltage A		-0.5	+6.5	V
V <sub>CC(B)</sub>	supply voltage B		-0.5	+6.5	V
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
Vo	output voltage	Active mode	<u>[1][2][3]</u> _0.5	$V_{CCO} + 0.5$	V
		Power-down or 3-state mode	<u>[1]</u> –0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
I <sub>OK</sub>	output clamping current	V <sub>O</sub> < 0 V	-50	-	mA
lo	output current	$V_{O} = 0 V$ to $V_{CCO}$	[2]	±50	mA
I <sub>CC</sub>	supply current	I <sub>CC(A)</sub> or I <sub>CC(B)</sub>	-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 \ ^{\circ}C \ to \ +125 \ ^{\circ}C$	[4] _	250	mW

[1] The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed.

[2]  $V_{CCO}$  is the supply voltage associated with the output.

[3]  $V_{CCO}$  + 0.5 V should not exceed 6.5 V.

[4] For TSSOP8 package: above 55 °C the value of P<sub>tot</sub> derates linearly with 2.5 mW/K.

For XSON8 and XSON8U packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

## 9. Recommended operating conditions

Table 6.	Recommended operating conditions <sup>[1][2]</sup>										
Symbol	Parameter	Conditions	Min	Max	Unit						
V <sub>CC(A)</sub>	supply voltage A		1.2	3.6	V						
V <sub>CC(B)</sub>	supply voltage B		1.65	5.5	V						
VI	input voltage		0	5.5	V						
Vo	output voltage	Power-down or 3-state mode; $V_{CC(A)} = 1.2 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$									
		A port	0	3.6	V						
		B port	0	5.5	V						
T <sub>amb</sub>	ambient temperature		-40	+125	°C						
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC(A)} = 1.2 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$	-	40	ns/V						

[1] The A and B sides of an unused I/O pair must be held in the same state, both at  $V_{CCI}$  or both at GND.

[2]  $V_{CC(A)}$  must be less than or equal to  $V_{CC(B)}$ .

## **10. Static characteristics**

#### Table 7. Typical static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); T<sub>amb</sub> = 25 °C.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>ОН</sub>	HIGH-level output voltage	A port; $V_{CC(A)}$ = 1.2 V; $I_O$ = -20 $\mu$ A		-	1.1	-	V
V <sub>OL</sub>	LOW-level output voltage	A port; $V_{CC(A)}$ = 1.2 V; $I_0$ = 20 $\mu$ A		-	0.09	-	V
I <sub>I</sub>	input leakage current	OE input; V <sub>I</sub> = 0 V to 3.6 V; V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V		-	-	±1	μA
I <sub>OZ</sub>	OFF-state output current	A or B port; $V_O = 0$ V to $V_{CCO}$ ; $V_{CC(A)} = 1.2$ V to 3.6 V; $V_{CC(B)} = 1.65$ V to 5.5 V	<u>[1]</u>	-	-	±1	μA
I <sub>OFF</sub>	power-off leakage current	A port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 0 V to 5.5 V		-	-	±1 +1	μA
		B port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 5.5 V; V <sub>CC(B)</sub> = 0 V; V <sub>CC(A)</sub> = 0 V to 3.6 V		-	-	±1	μA
I <sub>CC</sub>	supply current	$V_I = 0 V \text{ or } V_{CCI}; I_O = 0 A$	[2]				
		$I_{CC(A)}$ ; $V_{CC(A)} = 1.2$ V; $V_{CC(B)} = 1.65$ V to 5.5 V		-	0.05	-	μA
		$I_{CC(B)}$ ; $V_{CC(A)} = 1.2$ V; $V_{CC(B)} = 1.65$ V to 5.5 V		-	3.3	-	μΑ
		$I_{CC(A)} + I_{CC(B)}$ ; $V_{CC(A)} = 1.2$ V; $V_{CC(B)} = 1.65$ V to 5.5 V		-	3.5	-	μA
CI	input capacitance	OE input; $V_{CC(A)}$ = 1.2 V to 3.6 V; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	1.0	-	pF
C <sub>I/O</sub>	input/output	A port; $V_{CC(A)}$ = 1.2 V to 3.6 V; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	4.0	-	pF
	capacitance	B port; $V_{CC(A)} = 1.2$ V to 3.6 V; $V_{CC(B)} = 1.65$ V to 5.5 V		-	7.5	-	pF

[1]  $V_{CCO}$  is the supply voltage associated with the output.

[2]  $V_{CCI}$  is the supply voltage associated with the input.

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#### Dual supply translating transceiver; auto direction sensing; 3-state

#### Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		<b>−40</b> °C to	o +85 °C	<b>−40 °C to</b>	+125 °C	Unit
				Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	A or B port and OE input	<u>[1]</u>					
	input voltage	$V_{CC(A)} = 1.2 V \text{ to } 3.6 V;$ $V_{CC(B)} = 1.65 V \text{ to } 5.5 V$		0.65V <sub>CCI</sub>	-	0.65V <sub>CCI</sub>	-	V
V <sub>IL</sub>	LOW-level	A or B port and OE input	[1]					
	input voltage	$V_{CC(A)} = 1.2 \text{ V to } 3.6 \text{ V};$ $V_{CC(B)} = 1.65 \text{ V to } 5.5 \text{ V}$		-	0.35V <sub>CCI</sub>	-	0.35V <sub>CCI</sub>	V
V <sub>OH</sub>	HIGH-level	I <sub>O</sub> = -20 μA	[2]					
	output voltage	A port; $V_{CC(A)} = 1.4$ V to 3.6 V		$V_{CCO}-0.4$	-	$V_{CCO}-0.4$	-	V
		B port; $V_{CC(B)}$ = 1.65 V to 5.5 V		$V_{CCO}-0.4$	-	$V_{CCO}-0.4$		V
OL	LOW-level output voltage	I <sub>O</sub> = 20 μA	[2]					
		A port; $V_{CC(A)} = 1.4$ V to 3.6 V		-	0.4	-	0.4	V
		B port; $V_{CC(B)}$ = 1.65 V to 5.5 V		-	0.4	-	0.4	V
lı	input leakage current	$\begin{array}{l} \text{OE input; V}_{I} = 0 \text{ V to } 3.6 \text{ V;} \\ \text{V}_{\text{CC}(A)} = 1.2 \text{ V to } 3.6 \text{ V;} \\ \text{V}_{\text{CC}(B)} = 1.65 \text{ V to } 5.5 \text{ V} \end{array}$		-	±2	-	±5	μA
I <sub>OZ</sub>	OFF-state output current	A or B port; $V_O = 0$ V or $V_{CCO}$ ; $V_{CC(A)} = 1.2$ V to 3.6 V; $V_{CC(B)} = 1.65$ V to 5.5 V	[2]	-	±2	-	±10	μΑ
I <sub>OFF</sub>	power-off leakage	A port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 0 V to 5.5 V		-	±2	-	±10	μA
	current	B port; V <sub>1</sub> or V <sub>0</sub> = 0 V to 5.5 V; V <sub>CC(B)</sub> = 0 V; V <sub>CC(A)</sub> = 0 V to 3.6 V		-	±2	-	±10	μA

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#### Dual supply translating transceiver; auto direction sensing; 3-state

Symbol	Parameter	Conditions	-40 °C t	to +85 °C	-40 °C to	o +125 °C	Unit
			Min	Max	Min	Max	
I <sub>CC</sub>	supply current	$V_{I} = 0 V \text{ or } V_{CCI}; I_{O} = 0 A$ [1]					
		I <sub>CC(A)</sub>					
		OE = LOW; V <sub>CC(A)</sub> = 1.4 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	3	-	15	μA
		OE = HIGH; V <sub>CC(A)</sub> = 1.4 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	3	-	20	μA
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	-	2	-	15	μΑ
		$V_{CC(A)} = 0 V; V_{CC(B)} = 5.5 V$	-	-2	-	-15	μΑ
		I <sub>CC(B)</sub>					
		OE = LOW; V <sub>CC(A)</sub> = 1.4 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	5	-	15	μA
		OE = HIGH; V <sub>CC(A)</sub> = 1.4 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	5	-	20	μA
		$V_{CC(A)} = 3.6 \text{ V}; V_{CC(B)} = 0 \text{ V}$	-	-2	-	-15	μA
		$V_{CC(A)} = 0 \text{ V}; V_{CC(B)} = 5.5 \text{ V}$	-	2	-	15	μΑ
		$I_{CC(A)} + I_{CC(B)}$					
		$V_{CC(A)} = 1.4 V \text{ to } 3.6 V;$ $V_{CC(B)} = 1.65 V \text{ to } 5.5 V$	-	8	-	40	μΑ

#### Table 8. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

[1]  $V_{CCI}$  is the supply voltage associated with the input.

[2]  $V_{CCO}$  is the supply voltage associated with the output.

## **11. Dynamic characteristics**

 Table 9.
 Typical dynamic characteristics for temperature 25 °C<sup>[1]</sup>

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7; for waveforms see Figure 5 and Figure 6.

Symbol	Parameter	Conditions				Unit		
				1.8 V	2.5 V	3.3 V	5.0 V	
$V_{CC(A)} = 1$	1.2 V; T <sub>amb</sub> = 25 °C							
t <sub>pd</sub>	propagation delay	A to B		5.9	4.8	4.4	4.2	ns
		B to A		5.6	4.8	4.5	4.4	ns
t <sub>en</sub>	enable time	OE to A, B		0.5	0.5	0.5	0.5	μS
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	6.9	6.9	6.9	6.9	ns
		OE to B; no external load	[2]	9.5	8.6	8.5	8.0	ns
		OE to A		81	69	83	68	ns
		OE to B		81	69	83	68	ns
t <sub>t</sub>	transition time	A port		4.0	4.0	4.1	4.1	ns
		B port		2.6	2.0	1.7	1.4	ns

vonages a	are referenced to Giv	D (ground = 0 v), for les	i circuit see	e <u>Figure 7</u> , i	or wavelorms	s see <u>Figure s</u>	and <mark>Figure</mark>	<u>; 0</u> .
Symbol	Parameter	Conditions			Unit			
				1.8 V	2.5 V	3.3 V	5.0 V	
t <sub>sk(o)</sub>	output skew time	between channels	<u>[3]</u>	0.2	0.2	0.2	0.2	ns
t <sub>W</sub>	pulse width	data inputs		15	13	13	13	ns
f <sub>data</sub>	data rate			70	80	80	80	Mbps

#### Typical dynamic characteristics for temperature 25 °C[1] ... continued Table 9.

Voltages a referenced to GND (around = 0.V); for test circuit see Figure 7; for waveforms see Figure 5 and Figure 6

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

ten is the same as tPZL and tPZH.

 $t_{\text{dis}}$  is the same as  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}.$ 

 $t_{t}$  is the same as  $t_{\text{THL}}$  and  $t_{\text{TLH}}$ 

[2] Delay between OE going LOW and when the outputs are actually disabled.

Skew between any two outputs of the same package switching in the same direction. [3]

#### Table 10. Dynamic characteristics for temperature range –40 °C to +85 °C[1]

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 7; for wave forms see Figure 5 and Figure 6.

Symbol	Parameter	Conditions					Vcc	C(B)				Unit
				1.8 V ±	0.15 V	2.5 V :	± 0.2 V	3.3 V :	± 0.3 V	5.0 V -	± 0.5 V	
				Min	Max	Min	Max	Min	Max	Min	Max	
$V_{CC(A)} =$	1.5 V $\pm$ 0.1 V											
t <sub>pd</sub>	propagation	A to B		1.4	12.9	1.2	10.1	1.1	10.0	0.8	9.9	ns
	delay	B to A		0.9	14.2	0.7	12.0	0.4	11.7	0.3	13.7	ns
t <sub>en</sub>	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μs
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	1.0	11.9	1.0	11.9	1.0	11.9	1.0	11.9	ns
		OE to B; no external load	[2]	1.0	16.9	1.0	15.2	1.0	14.1	1.0	13.8	ns
		OE to A		-	320	-	260	-	260	-	280	ns
		OE to B		-	-	200	-	200	-	200	-	ns
t <sub>t</sub>	transition time	A port		0.9	5.1	0.9	5.1	0.9	5.1	0.9	5.1	ns
		B port		0.9	4.7	0.6	3.2	0.5	2.5	0.4	2.7	ns
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	0.5	-	0.5	-	0.5	-	0.5	ns
t <sub>W</sub>	pulse width	data inputs		25	-	25	-	25	-	25	-	ns
f <sub>data</sub>	data rate			-	40	-	40	-	40	-	40	Mbps
$V_{CC(A)} =$	$\textbf{1.8 V} \pm \textbf{0.15 V}$											
t <sub>pd</sub>	propagation	A to B		1.6	11.0	1.4	7.7	1.3	6.8	1.2	6.5	ns
	delay	B to A		1.5	12.0	1.3	8.4	1.0	7.6	0.9	7.1	ns
t <sub>en</sub>	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μS
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	1.0	11.0	1.0	11.0	1.0	11.0	1.0	11.0	ns
		OE to B; no external load	[2]	1.0	15.4	1.0	13.5	1.0	12.4	1.0	12.1	ns
		OE to A		-	260	-	230	-	230	-	230	ns
		OE to B		-	200	-	200	-	200	-	200	ns
t <sub>t</sub>	transition	A port		0.8	4.1	0.8	4.1	0.8	4.1	0.8	4.1	ns
	time	B port		0.9	4.7	0.6	3.2	0.5	2.5	0.4	2.7	ns

Symbol	Parameter	Conditions		V <sub>CC(B)</sub>							Unit	
				<b>1.8 V</b> ±	0.15 V	2.5 V			± 0.3 V	5.0 V :	± 0.5 V	-
				Min	Max	Min	Max	Min	Max	Min	Max	-
t <sub>sk(o)</sub>	output skew time	between channels	<u>[3]</u>	-	0.5	-	0.5	-	0.5	-	0.5	ns
t <sub>W</sub>	pulse width	data inputs		20	-	17	-	17	-	17	-	ns
f <sub>data</sub>	data rate			-	49	-	60	-	60	-	60	Mbps
V <sub>CC(A)</sub> =	$\textbf{2.5 V} \pm \textbf{0.2 V}$											
t <sub>pd</sub>	propagation	A to B		-	-	1.1	6.3	1.0	5.2	0.9	4.7	ns
	delay	B to A		-	-	1.2	6.6	1.1	5.1	0.9	4.4	ns
t <sub>en</sub>	enable time	OE to A, B		-	-	-	1.0	-	1.0	-	1.0	μS
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	-	1.0	9.2	1.0	9.2	1.0	9.2	ns
		OE to B; no external load	[2]	-	-	1.0	11.9	1.0	10.7	1.0	10.2	ns
		OE to A		-	-	-	200	-	200	-	200	ns
	OE to B		-	-	-	200	-	200	-	200	ns	
t <sub>t</sub>	transition	A port		-	-	0.7	3.0	0.7	3.0	0.7	3.0	ns
time	time	B port		-	-	0.7	3.2	0.5	2.5	0.4	2.7	ns
t <sub>sk(o)</sub>	output skew time	between channels	<u>[3]</u>	-	-	-	0.5	-	0.5	-	0.5	ns
t <sub>W</sub>	pulse width	data inputs		-	-	12	-	10	-	10	-	ns
f <sub>data</sub>	data rate			-	-	-	85	-	100	-	100	Mbp
V <sub>CC(A)</sub> =	3.3 V $\pm$ 0.3 V											
t <sub>pd</sub>	propagation	A to B		-	-	-	-	0.9	4.7	0.8	4.0	ns
	delay	B to A		-	-	-	-	1.0	4.9	0.9	3.8	ns
t <sub>en</sub>	enable time	OE to A, B		-	-	-	-	-	1.0	-	1.0	μS
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	-	-	-	1.0	9.2	1.0	9.2	ns
		OE to B; no external load	[2]	-	-	-	-	1.0	10.1	1.0	9.6	ns
		OE to A		-	-	-	-	-	260	-	260	ns
		OE to B		-	-	-	-	-	200	-	200	ns
t <sub>t</sub>	transition	A port		-	-	-	-	0.7	2.5	0.7	2.5	ns
	time	B port		-	-	-	-	0.5	2.5	0.4	2.7	ns
t <sub>sk(o)</sub>	output skew time	between channels	<u>[3]</u>	-	-	-	-	-	0.5	-	0.5	ns
t <sub>W</sub>	pulse width	data inputs		-	-	-	-	10	-	10	-	ns
f <sub>data</sub>	data rate							-	100	-	100	Mbps

 Table 10.
 Dynamic characteristics for temperature range -40 °C to +85 °C[1] ... continued

 $\label{eq:tpd} [1] \quad t_{pd} \text{ is the same as } t_{PLH} \text{ and } t_{PHL}.$ 

 $t_{en}$  is the same as  $t_{\text{PZL}}$  and  $t_{\text{PZH}}.$ 

 $t_{\text{dis}}$  is the same as  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}.$ 

 $t_{t}$  is the same as  $t_{\text{THL}}$  and  $t_{\text{TLH}}.$ 

[2] Delay between OE going LOW and when the outputs are actually disabled.

[3] Skew between any two outputs of the same package switching in the same direction.

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### Dual supply translating transceiver; auto direction sensing; 3-state

Symbol	Parameter	Conditions						$\label{eq:VCC(B)} \frac{V_{CC(B)}}{1.8 \ V \pm 0.15 \ V} \ 2.5 \ V \pm 0.2 \ V \ 3.3 \ V \pm 0.3 \ V \ 5.0 \ V \pm 0.5$						
				<b>1.8 V</b> ±	0.15 V	<b>2.5 V</b> :	± 0.2 V	<b>3.3 V</b> :	± 0.3 V	5.0 V :	± 0.5 V			
				Min	Max	Min	Max	Min	Max	Min	Max			
V <sub>CC(A)</sub> =	1.5 V $\pm$ 0.1 V													
t <sub>pd</sub>	propagation	A to B		1.4	15.9	1.2	13.1	1.1	13.0	0.8	12.9	ns		
	delay	B to A		0.9	17.2	0.7	15.0	0.4	14.7	0.3	16.7	ns		
t <sub>en</sub>	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μs		
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	1.0	12.5	1.0	12.5	1.0	12.5	1.0	12.5	ns		
		OE to B; no external load	[2]	1.0	18.1	1.0	16.2	1.0	14.9	1.0	14.6	ns		
		OE to A		-	340	-	280	-	280	-	300	ns		
		OE to B		-	220	-	220	-	220	-	220	ns		
t <sub>t</sub>	transition	A port		0.9	7.1	0.9	7.1	0.9	7.1	0.9	7.1	ns		
	time	B port		0.9	6.5	0.6	5.2	0.5	4.8	0.4	4.7	ns		
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	0.5	-	0.5	-	0.5	-	0.5	ns		
t <sub>W</sub>	pulse width	data inputs		25	-	25	-	25	-	25	-	ns		
f <sub>data</sub>	data rate			-	40	-	40	-	40	-	40	Mbp		
V <sub>CC(A)</sub> =	$\textbf{1.8 V} \pm \textbf{0.15 V}$													
t <sub>pd</sub>	propagation	A to B		1.6	14.0	1.4	10.7	1.3	9.8	1.2	9.5	ns		
	delay	B to A		1.5	15.0	1.3	11.4	1.0	10.6	0.9	10.1	ns		
en	enable time	OE to A, B		-	1.0	-	1.0	-	1.0	-	1.0	μS		
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	1.0	11.5	1.0	11.5	1.0	11.5	1.0	11.5	ns		
		OE to B; no external load	[2]	1.0	16.5	1.0	14.5	1.0	13.3	1.0	12.7	ns		
		OE to A		-	280	-	250	-	250	-	250	ns		
		OE to B		-	220	-	220	-	220	-	220	ns		
t <sub>t</sub>	transition	A port		0.8	6.2	0.8	6.1	0.8	6.1	0.8	6.1	ns		
	time	B port		0.9	5.8	0.6	5.2	0.5	4.8	0.4	4.7	ns		
t <sub>sk(o)</sub>	output skew time	between channels	[3]	-	0.5	-	0.5	-	0.5	-	0.5	ns		
w	pulse width	data inputs		22	-	19	-	19	-	19	-	ns		
data	data rate			-	45	-	55	-	55	-	55	Mbp		
V <sub>CC(A)</sub> =	$\textbf{2.5 V} \pm \textbf{0.2 V}$													
t <sub>pd</sub>	propagation	A to B		-	-	1.1	9.3	1.0	8.2	0.9	7.7	ns		
	delay	B to A		-	-	1.2	9.6	1.1	8.1	0.9	7.4	ns		
t <sub>en</sub>	enable time	OE to A, B		-	-	-	1.0	-	1.0	-	1.0	μs		
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	-	1.0	9.6	1.0	9.6	1.0	9.6	ns		
		OE to B; no external load	[2]	-	-	1.0	12.6	1.0	11.4	1.0	10.8	ns		
		OE to A		-	-	-	220	-	220	-	220	ns		
		OE to B		-	-	-	220	-	220	-	220	ns		
t	transition	A port		-	-	0.7	5.0	0.7	5.0	0.7	5.0	ns		
	time	B port		-	-	0.7	4.6	0.5	4.8	0.4	4.7	ns		

 Table 11. Dynamic characteristics for temperature range -40 °C to +125 °C<sup>[1]</sup>

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Symbol	Parameter	Conditions		V <sub>CC(B)</sub>								Unit
				<b>1.8 V</b> ±	8 V $\pm$ 0.15 V		± 0.2 V	3.3 V $\pm$ 0.3 V		5.0 V $\pm$ 0.5 V		
				Min	Max	Min	Max	Min	Max	Min	Max	
t <sub>sk(o)</sub>	output skew time	between channels	<u>[3]</u>	-	-	-	0.5	-	0.5	-	0.5	ns
t <sub>W</sub>	pulse width	data inputs;		-	-	14	-	13	-	10	-	ns
f <sub>data</sub>	data rate			-	-	-	75	-	80	-	100	Mbps
V <sub>CC(A)</sub> =	3.3 V $\pm$ 0.3 V											
t <sub>pd</sub> propagation delay	propagation	A to B		-	-	-	-	0.9	7.7	0.8	7.0	ns
	delay	B to A		-	-	-	-	1.0	7.9	0.9	6.8	ns
t <sub>en</sub>	enable time	OE to A, B		-	-	-	-	-	1.0	-	1.0	μS
t <sub>dis</sub>	disable time	OE to A; no external load	[2]	-	-	-	-	1.0	9.5	1.0	9.5	ns
		OE to B; no external load	[2]	-	-	-	-	1.0	10.7	1.0	9.6	ns
		OE to A		-	-	-	-	-	280	-	280	ns
		OE to B		-	-	-	-	-	220	-	220	ns
t <sub>t</sub>	transition	A port		-	-	-	-	0.7	4.5	0.7	4.5	ns
	time	B port		-	-	-	-	0.5	4.1	0.4	4.7	ns
t <sub>sk(o)</sub>	output skew time	between channels	<u>[3]</u>	-	-	-	-	-	0.5	-	0.5	ns
t <sub>W</sub>	pulse width	data inputs		-	-	-	-	10	-	10	-	ns
f <sub>data</sub>	data rate			-	-	-	-	-	100	-	100	Mbps

**Table 11.** Dynamic characteristics for temperature range  $-40 \degree$ C to  $+125 \degree$ C<sup>[1]</sup> ...continued Voltages are referenced to GND (ground = 0 V): for test circuit see Figure 7: for wave forms see Figure 5 and Figure 6

[1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .  $t_{en} \mbox{ is the same as } t_{PZL} \mbox{ and } t_{PZH}.$ 

 $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .  $t_{t}$  is the same as  $t_{\text{THL}}$  and  $t_{\text{TLH.}}$ 

[2] Delay between OE going LOW and when the outputs are actually disabled.

[3] Skew between any two outputs of the same package switching in the same direction.

#### Dual supply translating transceiver; auto direction sensing; 3-state

Symbol	Parameter	Conditions	V <sub>CC(A)</sub>							
			1.2 V	1.2 V	1.5 V	1.8 V	2.5 V	2.5 V	3.3 V	
						V <sub>CC(B)</sub>				
			1.8 V	5.0 V	1.8 V	1.8 V	2.5 V	5.0 V	3.3 V to 5.0 V	
T <sub>amb</sub> = 2	5 °C									
C <sub>PD</sub>	power dissipation capacitance	outputs enabled; $OE = V_{CC(A)}$								
		A port: (direction A to B)	5	5	5	5	5	5	5	pF
		A port: (direction B to A)	8	8	8	8	8	8	8	pF
		B port: (direction A to B)	18	18	18	18	18	18	18	pF
		B port: (direction B to A)	13	16	12	12	12	12	13	pF
		outputs disabled; OE = GND								
		A port: (direction A to B)	0.12	0.12	0.04	0.05	0.08	0.08	0.07	pF
		A port: (direction B to A)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
		B port: (direction A to B)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF
		B port: (direction B to A)	0.07	0.09	0.07	0.07	0.05	0.09	0.09	pF

## **Table 12.** Typical power dissipation capacitance Voltages are referenced to GND (ground = 0 V).[1][2]

[1]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

 $C_L$  = load capacitance in pF;

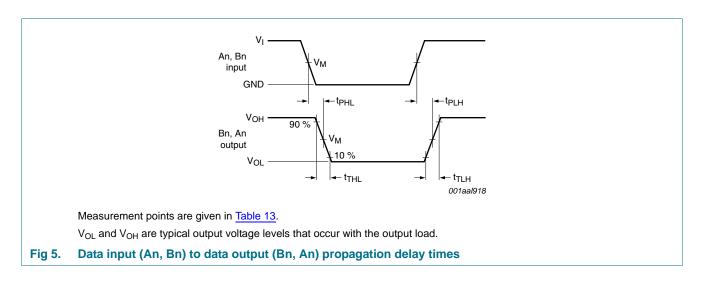
V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[2]  $f_i = 10 \text{ MHz}$ ;  $V_I = \text{GND}$  to  $V_{CC}$ ;  $t_f = t_f = 1 \text{ ns}$ ;  $C_L = 0 \text{ pF}$ ;  $R_L = \infty \Omega$ .

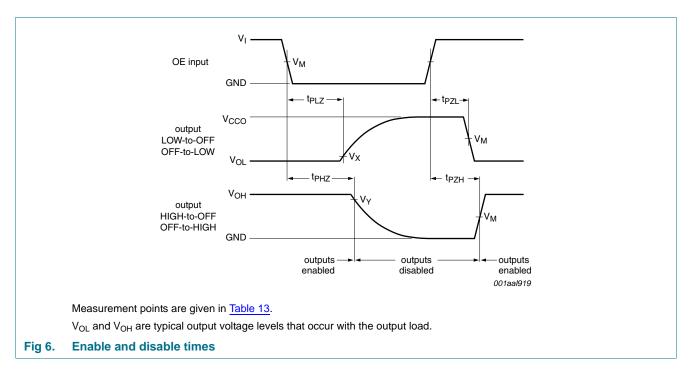
## 12. Waveforms



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# NXB0102

#### Dual supply translating transceiver; auto direction sensing; 3-state



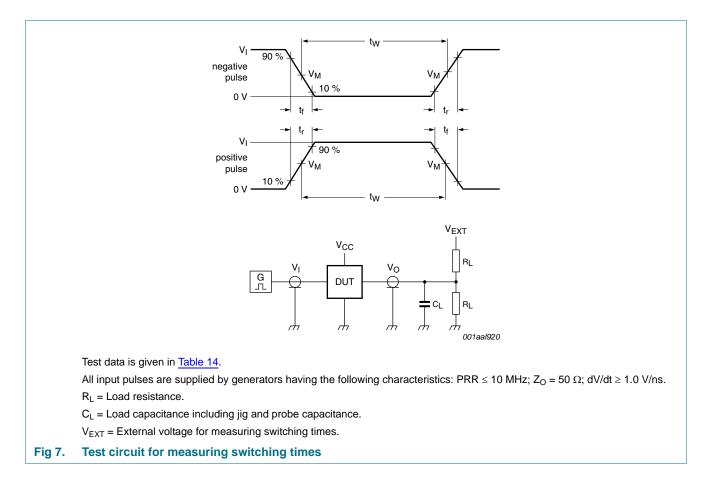
#### Table 13. Measurement points<sup>[1]</sup>

Table 10. Measuren				
Supply voltage	Input	Output		
V <sub>cco</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
1.2 V	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> – 0.1 V
$1.5~\text{V}\pm0.1~\text{V}$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.1 V	V <sub>OH</sub> – 0.1 V
$1.8 \text{ V} \pm 0.15 \text{ V}$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V
$2.5~\text{V}\pm0.2~\text{V}$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V
$3.3 \text{ V} \pm 0.3 \text{ V}$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V
$5.0~\text{V}\pm0.5~\text{V}$	0.5V <sub>CCI</sub>	0.5V <sub>CCO</sub>	V <sub>OL</sub> + 0.3 V	V <sub>OH</sub> – 0.3 V

[1]  $V_{CCI}$  is the supply voltage associated with the input and  $V_{CCO}$  is the supply voltage associated with the output.

# NXB0102

#### Dual supply translating transceiver; auto direction sensing; 3-state



#### Table 14. Test data

Supply voltage	je	Input		Load		V <sub>EXT</sub>		
V <sub>CC(A)</sub>	V <sub>CC(B)</sub>	۷ <mark>[1]</mark>	∆t/∆V	CL	R <sub>L</sub> [2]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ<sup>[3]</sup></sub>
1.2 V to 3.6 V	1.65 V to 5.5 V	V <sub>CCI</sub>	$\leq$ 1.0 ns/V	15 pF	50 kΩ, 1 MΩ	open	open	2V <sub>CCO</sub>

[1] V<sub>CCI</sub> is the supply voltage associated with the input.

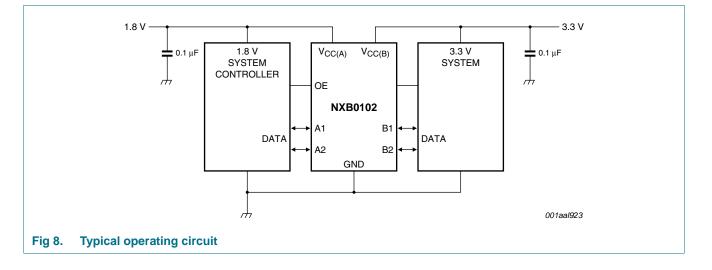
[2] For measuring data rate, pulse width, propagation delay and output rise and fall measurements,  $R_L = 1 M\Omega$ ; for measuring enable and disable times,  $R_L = 50 k\Omega$ .

[3]  $V_{CCO}$  is the supply voltage associated with the output.

## **13. Application information**

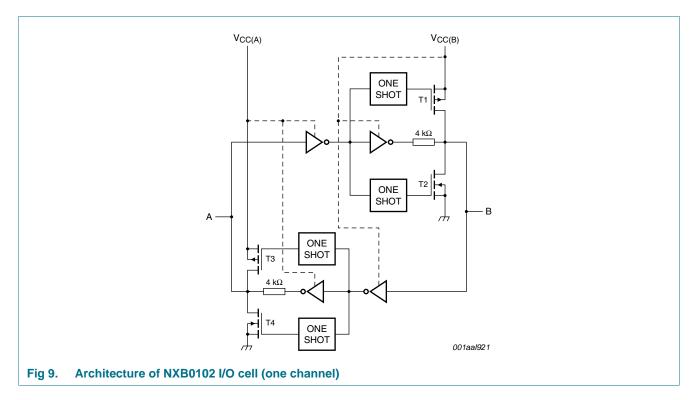
### **13.1 Applications**

Voltage level-translation applications. The NXB0102 can be used to interface between devices or systems operating at different supply voltages. See <u>Figure 8</u> for a typical operating circuit using the NXB0102.



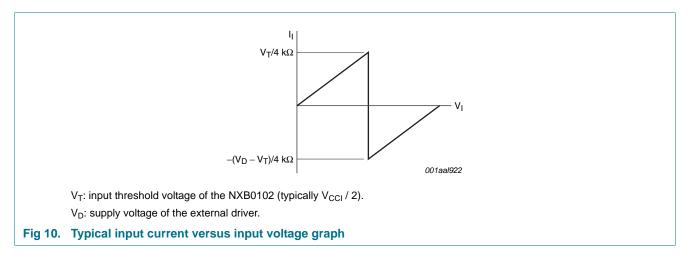
#### 13.2 Architecture

The architecture of the NXB0102 is shown in Figure 9. The device does not require an extra input signal to control the direction of data flow from A to B or from B to A. In a static state, the output drivers of the NXB0102 can maintain a defined output level, but the output architecture is designed to be weak, so that they can be overdriven by an external driver when data on the bus starts flowing in the opposite direction. The output of one-shot circuits detect rising or falling edges on the A or B ports. During a rising edge, the one-shot circuits turn on the PMOS transistors (T1, T3) for a short duration, accelerating the LOW-to-HIGH transition. Similarly, during a falling edge, the one-shot circuits turn on the NMOS transistors (T2, T4) for a short duration, accelerating the HIGH-to-LOW transition. During output transitions the typical output impedance is 70  $\Omega$  at V<sub>CCO</sub> = 1.2 V to 1.8 V, 50  $\Omega$  at V<sub>CCO</sub> = 1.8 V to 3.3 V and 40  $\Omega$  at V<sub>CCO</sub> = 3.3 V to 5.0 V.



#### 13.3 Input driver requirements

For correct operation, the device driving the data I/Os of the NXB0102 must have a minimum drive capability of  $\pm 2$  mA See <u>Figure 10</u> for a plot of typical input current versus input voltage.



#### 13.4 Power-up

During operation  $V_{CC(A)}$  must never be higher than  $V_{CC(B)}$ , however during power-up  $V_{CC(A)} \ge V_{CC(B)}$  does not damage the device, so either power supply can be ramped up first. There is no special power-up sequencing required. The NXB0102 includes circuitry that disables all output ports when either  $V_{CC(A)}$  or  $V_{CC(B)}$  is switched off.

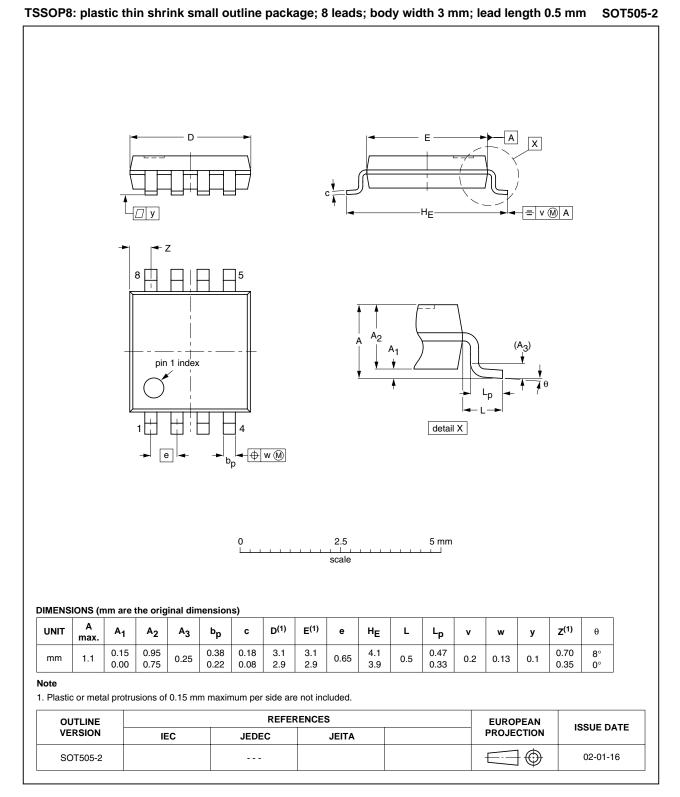
#### 13.5 Enable and disable

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state. The disable time ( $t_{dis}$  with no external load) indicates the delay between when OE goes LOW and when outputs actually become disabled. The enable time ( $t_{en}$ ) indicates the amount of time the user must allow for one one-shot circuitry to become operational after OE is taken HIGH. To ensure the high-impedance OFF-state during power-up or power-down, pin OE should be tied to GND through a pull-down resistor, the minimum value of the resistor is determined by the current-sourcing capability of the driver.

#### 13.6 Pull-up or pull-down resistors on I/O lines

As mentioned previously the NXB0102 is designed with low static drive strength to drive capacitive loads of up to 70 pF. To avoid output contention issues, any pull-up or pull-down resistors used must be above 50 k $\Omega$ . For this reason the NXB0102 is not recommended for use in open drain driver applications such as 1-Wire or I<sup>2</sup>C-bus. For these applications, the NXS0102 level translator is recommended.

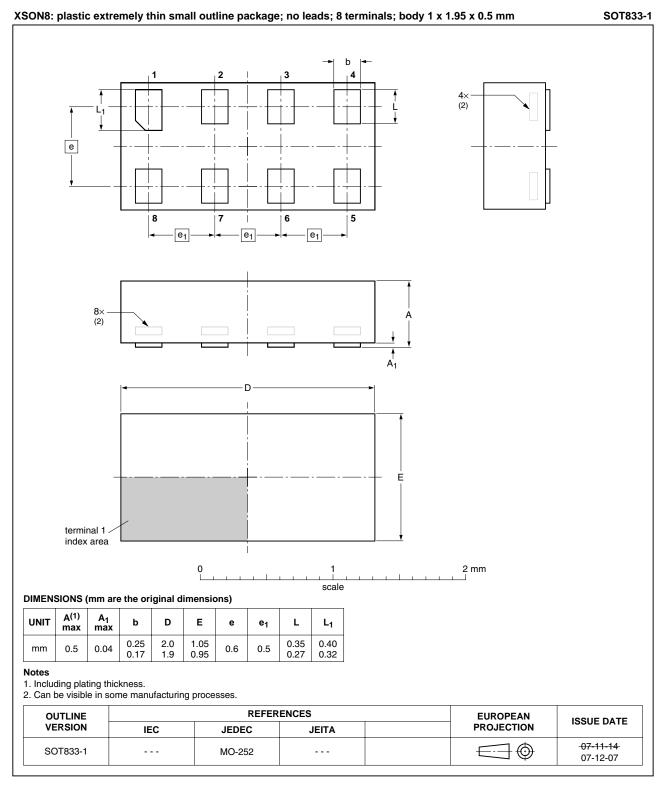
### 14. Package outline



#### Fig 11. Package outline SOT505-2 (TSSOP8)

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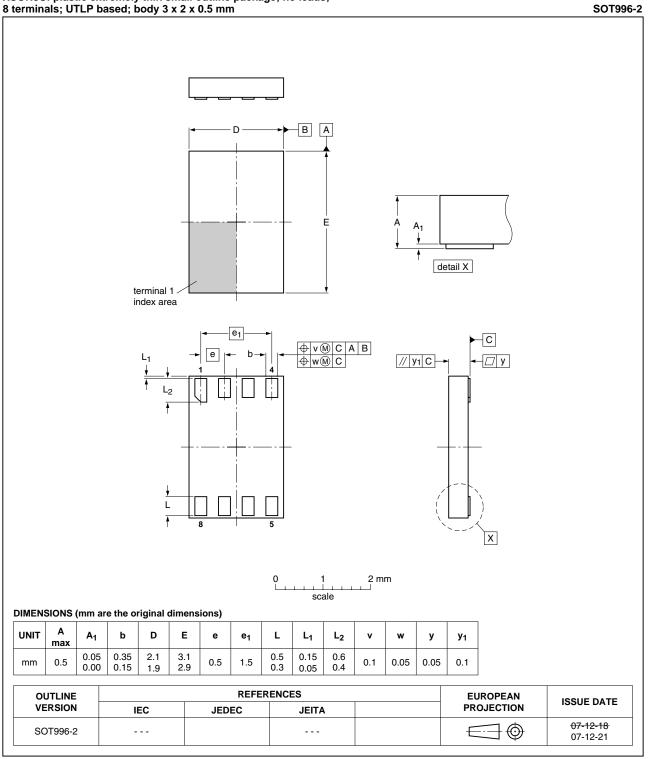
#### Dual supply translating transceiver; auto direction sensing; 3-state



#### Fig 12. Package outline SOT833-1 (XSON8)

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Dual supply translating transceiver; auto direction sensing; 3-state

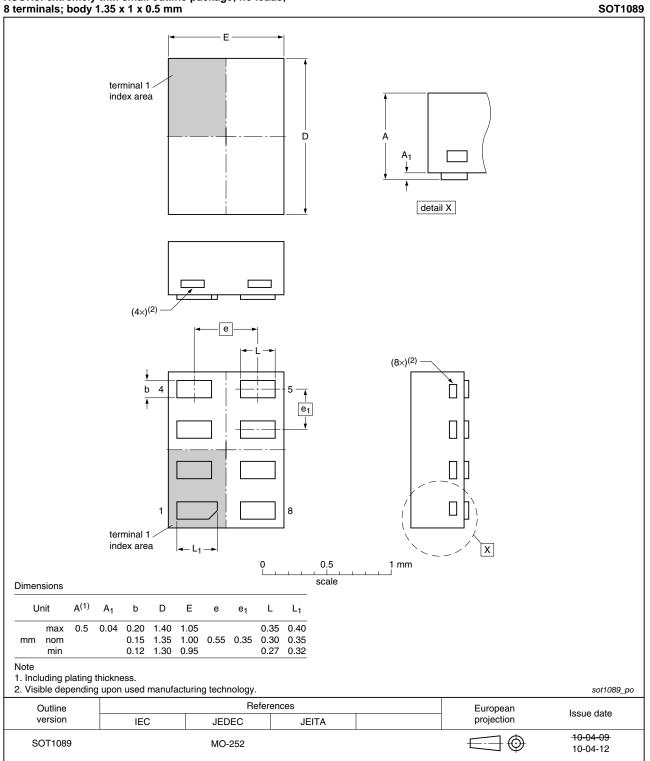


XSON8U: plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body 3 x 2 x 0.5 mm

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Fig 13. Package outline SOT996-2 (XSON8U)

Dual supply translating transceiver; auto direction sensing; 3-state



XSON8: extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm

Fig 14. Package outline SOT1089 (XSON8)

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## **15. Abbreviations**

Table 15.	Abbreviations
Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
PRR	Pulse Repetition Rate

## **16. Revision history**

Table 16. Revision his	story			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NXB0102 v.1	20100608	Product data sheet	-	-

## **17. Legal information**

#### 17.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions"

The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status [3] information is available on the Internet at URL http://www.nxp.com.

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#### Dual supply translating transceiver; auto direction sensing; 3-state

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